

# Single-Channel Power Distribution Switch

### **Description**

The FP6861E-C/E/F/H is a cost-effective, low voltage, single N-Channel MOSFET high-side power switch, optimized for self-powered and bus-powered Universal Serial Bus (USB) applications.

The FP6861E-C/E/F/H is equipped with a charge pump circuitry to drive the internal MOSFET switch. The switch's low  $R_{\rm DS(ON)}$  meets USB voltage drop requirement, and a flag output is available to indicate fault conditions to the local USB controller.

Additional features include soft-start to limit inrush current during plug-in, thermal shutdown to prevent catastrophic switch failure from high-current loads, and Under-Voltage Lockout (UVLO) to ensure that the device remains off unless there is a valid input voltage present. Besides, fault current is limited to specific current for FP6861E-C/E/F/H in single port in accordance with the USB power requirements. FP6861E-C/E/F/H will prevent reverse current when it is disabled and VOUT is higher than VIN.

The FP6861E-C/E/F/H is available in MSOP-8, SOP-8 and SOT-23-5 packages with smallest components.

### **Features**

- Compliant to USB Specifications
- Built-In Low RDS(ON) N-Channel MOSFET
- Output can be Forced Higher than Input (Off-State)
- Low Supply Current:
   65μA Typical at Switch On State
   0.1μA Typical at Switch Off State
- 2.7V to 5.5V Input Voltage Range
- Open-Drain Fault Flag Output
- Hot Plug-In Application (Soft-Start)
- 2.2V Typical Under-Voltage Lockout (UVLO)
- Current Limit Protection
- Thermal Shutdown Protection
- Reverse Current Flow Blocking (No Body Diode)
- Logic Level Enable Pin
- MSOP-8, SOP-8 and SOT-23-5 Packages
- RoHS Compliant
- UL NO.E322418 (Approved model: FP6861 Series)
- CB Test Certified, Ref. Certif. No. JPTUV-101402

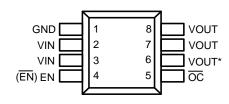
### **Applications**

- USB Bus/Self Powered Hub
- USB Peripheral
- ACPI Power Distribution
- Notebook, Motherboard PC
- Battery-Charger Circuit

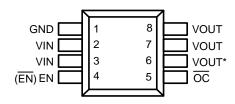


## **Pin Assignments**

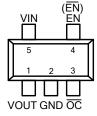
### MS Package (MSOP-8)



### SO Package (SOP-8)



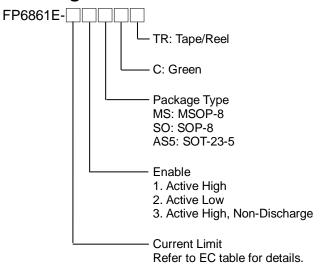
### AS5 Package (SOT-23-5)



<sup>\*</sup> The pin 6 should be considered as VOUT when circuit design and PCB layout, but it is NC pin actually.

Figure 1. Pin Assignment of FP6861E-C/E/F/H

## **Ordering Information**



#### Available Product List

FP6861E-F1MSCTR
FP6861E-F1SOCTR
FP6861E-F1AS5CTR
FP6861E-F2MSCTR
FP6861E-F2SOCTR
FP6861E-F2AS5CTR
FP6861E-F3MSCTR
FP6861E-F3SOCTR
FP6861E-F3AS5CTR
FP6861E-H1MSCTR
FP6861E-H1SOCTR
FP6861E-H1AS5CTR
FP6861E-H2MSCTR
FP6861E-H2SOCTR
FP6861E-H2AS5CTR
FP6861E-H3MSCTR
FP6861E-H3SOCTR
FP6861E-H3AS5CTR

### SOT-23-5 Marking

SO 1-23-5 Warking			
Part Number	Product Code	Part Number	Product Code
FP6861E-C1AS5C	FG7	FP6861E-F1AS5C	FH2
FP6861E-C2AS5C	FG8	FP6861E-F2AS5C	FH3
FP6861E-C3AS5C	FM7	FP6861E-F3AS5C	FM9
FP6861E-E1AS5C	FG9	FP6861E-H1AS5C	FH4
FP6861E-E2AS5C	FH1	FP6861E-H2AS5C	FH5
FP6861E-E3AS5C	FM8	FP6861E-H3AS5C	FN1



## **Typical Application Circuit**

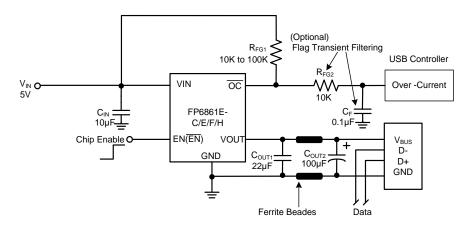
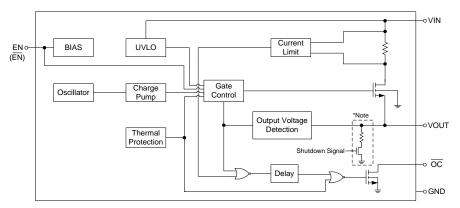


Figure 2. Typical Application Circuit

## **Functional Pin Description**

Pin Name	Pin Function
VIN	Input power supply.
VOUT	Switch output.
GND	Ground.
EN	Chip enable. Pull the pin high to enable IC; Pull the pin low to shutdown IC. Do not let the pin floating.
EN	Chip shutdown. Pull the pin high to shutdown IC; Pull the pin low to enable IC. Do not let the pin floating.
ōc	Open-drain fault flag output.

## **Block Diagram**



\*Note: There is no discharge circuit for FP6861E-x3xxx series.

Figure 3. Block Diagram



## Absolute Maximum Ratings (Note 1)

3	
• VIN, VOUT	0.3V to +6.5V
• EN ( <del>EN</del> )	0.3V to +6.5V
• <del>OC</del>	0.3V to +6.5V
<ul> <li>Power Dissipation @ T<sub>A</sub>=25°C, (P<sub>D</sub>)</li> </ul>	
MSOP-8	- 0.63W
SOP-8	· 0.91W
SOT-23-5	0.4W
<ul> <li>Package Thermal Resistance, (θ<sub>JA</sub>)</li> </ul>	
MSOP-8	- 160°C/W
SOP-8	110°C/W
SOT-23-5	250°C/W
<ul> <li>Package Thermal Resistance, (θ<sub>JC</sub>)</li> </ul>	
MSOP-8	- 75°C/W
SOP-8	- 39°C/W
SOT-23-5	130°C/W
• Junction Temperature	- +150°C
• Lead Temperature (Soldering,10 sec.)	- +260°C
Storage Temperature Range	65°C to +150°C
Note 1: Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent dama	ge to the device.
Recommended Operating Conditions	
• Supply Voltage (V <sub>IN</sub> )	+2.7V to +5.5V
Junction Temperature Range (T <sub>OPR</sub> )	
Operation Temperature Range (T <sub>OPR</sub> )	



## **Electrical Characteristics**

(V<sub>IN</sub>=5V, T<sub>A</sub>=25°C, unless otherwise specified.)

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Switch On Resistance	R <sub>DS(ON)</sub>	I <sub>OUT</sub> =100mA, MSOP-8,SOP-8 package		100		mΩ
	1 100(011)	I <sub>OUT</sub> =100mA, SOT-23-5 package		100		
Supply Current	I <sub>SW_ON</sub>	Switch on, V <sub>OUT</sub> = Open		65		μA
Зарргу Сапен	I <sub>SW_OFF</sub>	Switch off, V <sub>OUT</sub> = Open		0.1	1	μΛ
EN Threshold	V <sub>IL</sub>	Switch off			0.7	V
LIN THIESHOLD	V <sub>IH</sub>	Switch on	1.8			V
EN Input Current	I <sub>EN</sub>	V <sub>EN</sub> =Enable		0.01	0.1	μA
		R <sub>LOAD</sub> =1Ω, FP6861E-C	2.1	2.45	2.8	А
Current Limit		R <sub>LOAD</sub> =1Ω, FP6861E-E	1.5	1.75	2.1	А
Current Limit	I <sub>LIM</sub>	R <sub>LOAD</sub> =1Ω, FP6861E-F	0.7	1	1.35	Α
		R <sub>LOAD</sub> =1Ω, FP6861E-H	1.1	1.4	1.7	Α
	I <sub>SC_FB</sub>	V <sub>OUT</sub> =0V, Measured Prior to Thermal Shutdown, FP6861E-C		1.47		А
Short Circuit Fold-Back		V <sub>OUT</sub> =0V, Measured Prior to Thermal Shutdown, FP6861E-E		1.05		А
Current		V <sub>OUT</sub> =0V, Measured Prior to Thermal Shutdown, FP6861E-F		0.6		Α
		V <sub>OUT</sub> =0V, Measured Prior to Thermal Shutdown, FP6861E-H		0.84		А
Output Leakage Current	I <sub>LEAKAGE</sub>	$V_{EN}$ =Disable, $R_{LOAD}$ = $0\Omega$		0.5	1	μA
OC Output Resistance	R <sub>oc</sub>	I <sub>SINK</sub> =1mA		70		Ω
OC Off Current	I <sub>oc</sub>	V <sub>OC</sub> = 5V		0.01		μA
OC Delay Time	t <sub>D</sub>	From Fault Condition to OC Assertion		10		ms
Under-Voltage Lockout	V <sub>UVLO</sub>	V <sub>IN</sub> Increasing		2.2		V
Under-Voltage Hysteresis	$\Delta V_{UVLO}$	V <sub>IN</sub> Decreasing		0.2		V
Shutdown Pull Low Resistance (Note 2)	R <sub>PD</sub>			80		Ω
Thermal Shutdown Threshold (Note 3)	T <sub>SD</sub>			135		°C
Threshold (Note 3)	$\Delta T_{SD}$	Hysteresis		20		°C

Note 2: There is no resistor for FP6861E-x3xxx series.

Note 3: Guarantee by design.



## **Typical Performance Curves**

 $V_{\text{IN}} = V_{\text{OUT}} = 5\text{V}, \ C_{\text{IN}} = 100 \mu\text{F}, \ C_{\text{OUT}} = 120 \mu\text{F}, \ TA = +25 ^{\circ}\text{C}, \ unless \ otherwise noted}.$  This is measured by using FP6861E-C1AS5C.

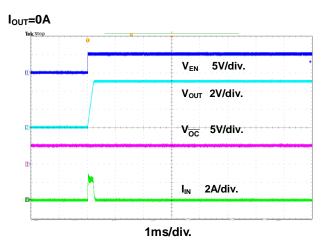


Figure 4. EN Start-Up with No Load

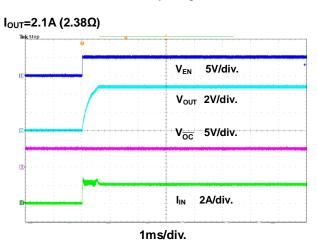


Figure 5. EN Start-Up with Heavy Load

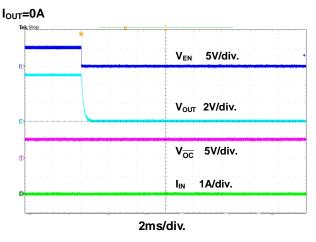


Figure 6. EN Power Off with No Load

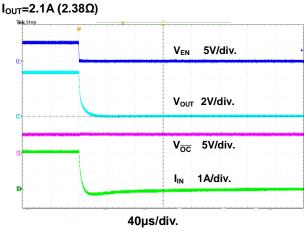


Figure 7. EN Power Off with Heavy Load

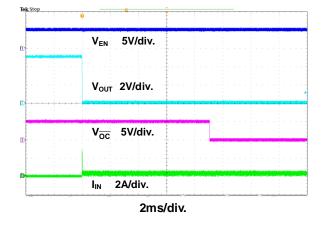


Figure 8. Inrush Short Circuit Response

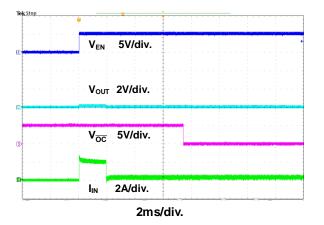


Figure 9. Short Circuit Response at Start Up



## **Typical Performance Curves (Continued)**

 $V_{\text{IN}} = V_{\text{OUT}} = 5\text{V}, \ C_{\text{IN}} = 100 \mu\text{F}, \ C_{\text{OUT}} = 120 \mu\text{F}, \ TA = +25 ^{\circ}\text{C}, \ unless otherwise noted}.$  This is measured by using FP6861E-C1AS5C.

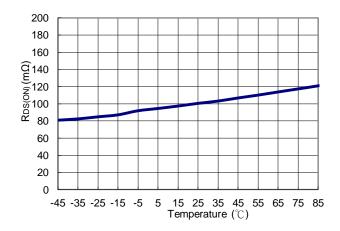


Figure 10. R<sub>DS(ON)</sub> vs. Temperature

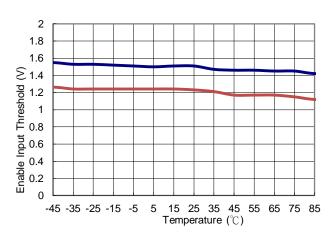


Figure 12. Enable Input Threshold vs. Temperature

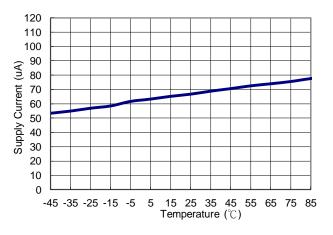


Figure 11. Supply Current vs. Temperature

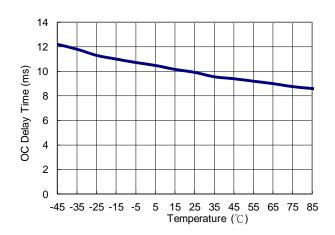


Figure 13. OC Delay Time vs. Temperature



### Application Information

The FP6861E-C/E/F/H is a single N-Channel MOSFET high-side power switch, optimized for self-powered and bus-powered Universal Serial Bus (USB) applications. The FP6861E-C/E/F/H operates from 2.7V to 5.5V input voltage range and provides low supply current. The switch's low  $R_{\rm DS(ON)},\ 100m\Omega,$  meets USB voltage drop requirements. It has one switch with enable control input. The switch has an error flag output to notify the USB controller when the current-limit, short-circuit or thermal-shutdown occurs.

#### **Under-Voltage Lockout**

Under-Voltage Lockout (UVLO) prevents the MOSFET switch from turning on until input voltage exceeds approximately 2.2V. If input voltage drops below approximately 2V, UVLO will turn off the MOSFET switch.

#### Thermal Shutdown

Thermal shutdown is employed to protect the device from damage if the die temperature exceeds safe margins mainly due to short-circuit or current-limit. Thermal shutdown will shut the switch off and cause the  $\overline{OC}$  output to go low.

#### **Reverse Current Blocking**

The USB specification does not allow an output device to source current back into the USB port. However, the FP6861E-C/E/F/H is designed to safely power noncompliant devices. When the device is disabled, the output will be switched to a high-impedance state, blocking reverse current flow from the output back to the input. The switch is bidirectional when it is enabled.

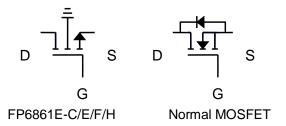
#### **Error Flag**

The FP6861E-C/E/F/H provides an open drain error flag output for the switch. For most applications, connect  $\overline{OC}$  to VIN through a pull-up resistor.  $\overline{OC}$  will go low when any following condition occurs:

- a. The thermal shutdown occurs.
- b. The switch is in current limit or short circuit conditions.

#### **Input and Output**

VIN is the power source connection to the internal circuitry and the drain of the MOSFET. VOUT is the source of the MOSFET. In typical application, current flows through the switch from VIN to VOUT toward the load. If VOUT is greater than VIN, current will flow from VOUT to VIN since the MOSFET is bidirectional. There is no parasitic body diode between drain and source of the MOSFET, and the FP6861E-C/E/F/H will prevent reverse current flow if VOUT externally forces a higher voltage than VIN when the output is disabled.



#### Soft Start for Hot Plug-In Application

In order to eliminate the upstream voltage drop caused by the large inrush current during hot-plug events, the "soft-start" feature effectively isolates the power source from extremely large capacitive loads, satisfying the USB voltage drop requirements.

### **Current Limit and Short-Circuit Protection**

The current limit circuitry prevents damage to the MOSFET switch and the hub downstream port but can deliver load current up to the current limit threshold through the switch of FP6861E-C/E/F/H. When a heavy load or short circuit is applied to an enabled switch, a large transient current may flow until the current limit circuitry responds. Once exceeds the current limit threshold, the device will enter constant current mode until the thermal shutdown occurs or the fault is removed.

#### **Fast Shutdown Load Discharge**

The FP6861E provides a pull down resistance when the device is off. The resistance could discharge the load capacitor fast (refer to the block diagram). (FP6861E-x3xxx series is non-discharge.)



## **Application Information (Continued)**

#### Supply Filter/Bypass Capacitor

The input capacitor must be at least  $1\mu F$  low-ESR ceramic capacitor connected from VIN to GND, but can be increased without limit. Output short may cause sufficient ringing on the input (from source lead inductance) to destroy the internal control circuitry. The input transient must not exceed 6.5V of the absolute maximum supply voltage even for a short duration.

#### **Output Filter Capacitor**

Output is recommended to use a  $22\mu F$  ceramic capacitor in parallel with a  $100\mu F$  electrolytic capacitor. Standard bypass methods should be used to minimize inductance and resistance between the bypass capacitor and the downstream connector which reduce EMI and decouple voltage drop caused when downstream cables are hot-insertion transients. Ferrite beads in series with  $V_{BUS}$ , the ground line and the  $0.1\mu F$  bypass capacitors at the power connector pins are recommended for EMI and ESD protection. The bypass capacitor should have a low dissipation factor to allow decoupling at higher frequencies.

#### **Power Dissipation**

The device's junction temperature depends on several factors, such as the load, PCB layout, ambient temperature and package type. However, the maximum output current must be decreased at higher ambient temperature to ensure the junction temperature does not exceed 125°C. With all possible conditions, the junction temperature must be within the range specified under operating conditions. Power dissipation can be calculated based on the output current and the  $R_{\text{DS(ON)}}$  of switch as below:

$$P_D = R_{DS(ON)} \times (I_{OUT})^2$$

Although the devices are rated by current limit, but the application may limit the amount of output current based on the total power dissipation and the ambient temperature. The final operating junction temperature for any set of conditions can be estimated by the following thermal equation:

$$P_{D(MAX)} = \frac{T_{J(MAX)} - T_A}{\theta_{JA}}$$

Where  $T_{J(MAX)}$  is the maximum junction temperature 125°C,  $T_A$  is the ambient temperature and the  $\theta_{JA}$  is the junction to ambient thermal resistance.

The junction to ambient thermal resistance  $\theta_{JA}$  is related to layout. For SOT-23-5 package, the thermal resistance  $\theta_{JA}$  is 250°C/W on the standard JEDEC 51-3 single-layer thermal test board.

#### **PCB Layout**

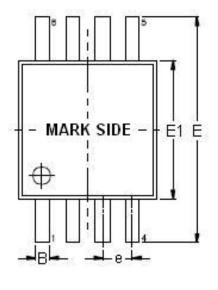
In order to meet the voltage drop and EMI requirements, careful PCB layout is necessary. The following guidelines must be considered:

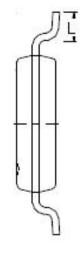
- Keep all V<sub>BUS</sub> traces as short as possible, and use at least 50-mil and 2 ounce copper for all V<sub>BUS</sub> traces.
- Locate the FP6861E-C/E/F/H as close to the output port as possible to limit switching noise.
- Locate the ceramic bypass capacitors as close to the VIN pins of the FP6861E-C/E/F/H as possible.
- Avoid vias as much as possible. If vias are necessary, make them as large as feasible.
- Place a ground plane under all circuitry to lower both resistance and inductance, and improve DC and transient performance (use a separate ground and power plans if possible).
- Place cuts in the ground plane between ports to help reducing the coupling of transients between ports.
- Locate the output capacitor and ferrite beads as close to the USB connectors as possible to lower impedance (mainly inductance) between the port and the capacitor, and improve transient load performance.



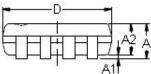
## **Outline Information**

### MSOP-8 Package (Unit: mm)

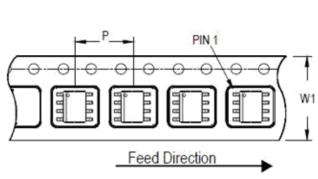


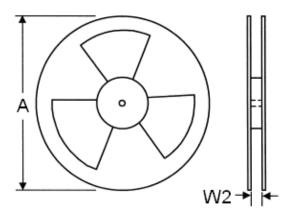


SYMBOLS	DIMENSION IN	MILLIMETER
UNIT	MIN	MAX
Α	0.75	1.10
A1	0.00	0.15
A2	0.75	0.95
В	0.25	0.35
D	2.90	3.10
E	4.80	5.00
E1	2.90	3.10
е	0.60	0.70
L	0.40	0.80



## **Carrier Dimensions**



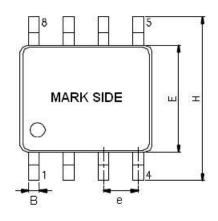


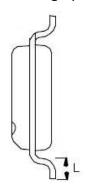
Tape Size	Pocket Pitch	Reel Size (A)		Reel Width	Empty Cavity	Units per Reel
(W1) mm	(P) mm	in	mm	(W2) mm	Length mm	
12	8	13	330	12.4	400~1000	3,000



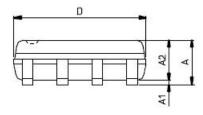
## **Outline Information (Continued)**

SOP-8 Package (Unit: mm)

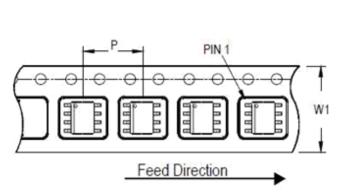


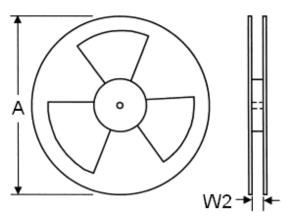


SYMBOLS	DIMENSION IN	MILLIMETER
UNIT	MIN	MAX
Α	1.35	1.75
A1	0.10	0.25
A2	1.25	1.50
В	0.31	0.51
D	4.80	5.00
Е	3.80	4.00
е	1.20	1.34
Н	5.80	6.20
L	0.40	1.27



## **Carrier Dimensions**



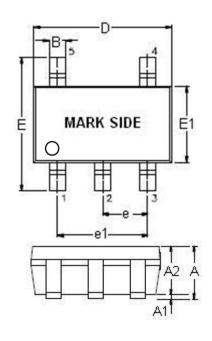


Tape Size	Pocket Pitch	Reel Size (A)		Reel Width	Empty Cavity	Units per Reel
(W1) mm	(P) mm	in	mm	(W2) mm	Length mm	
12	8	13	330	12.4	400~1000	2,500



## **Outline Information (Continued)**

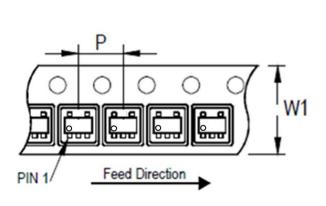
SOT-23-5 Package (Unit: mm)

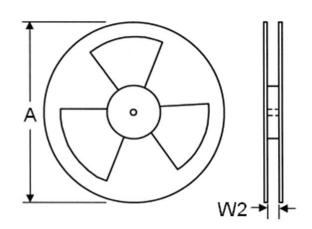




SYMBOLS	DIMENSION I	N MILLIMETER
UNIT	MIN	MAX
Α	0.90	1.45
A1	0.00	0.15
A2	0.90	1.30
В	0.30	0.50
D	2.80	3.00
E	2.60	3.00
E1	1.50	1.70
е	0.90	1.00
e1	1.80	2.00
Ĺ	0.30	0.60

### **Carrier Dimensions**





Tape Size	Pocket Pitch	Reel Size (A)		Reel Width	Empty Cavity	Units per Reel
(W1) mm	(P) mm	in	mm	(W2) mm	Length mm	
8	4	7	180	8.4	300~1000	3,000